

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officer

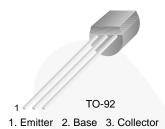


November 2014

KSC945 NPN Epitaxial Silicon Transistor

Features

- Audio Frequency Amplifier and High-Frequency OSC.
- Complimentary to KSA733
- Collector-Base Voltage: V_{CBO} = 60 V
- High Current Gain Bandwidth Product: f_T = 300 MHz (Tyical)
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



Ordering Information

Part Number	Top Mark	Package	Packing Method
KSC945YBU	C945	TO-92 3L	Bulk
KSC945YTA	C945	TO-92 3L	Ammo
KSC945GTA	C945	TO-92 3L	Ammo
KSC945CYTA	C945	TO-92 3L	Ammo
KSC945CGBU	C945	TO-92 3L	Bulk
KSC945CGTA	C945	TO-92 3L	Ammo

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	60	V
V _{CEO}	Collector-Emitter Voltage	50	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	150	mA
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to 150	°C

© 2002 Fairchild Semiconductor Corporation KSC945 Rev. 1.1.0

Thermal Characteristics(1)

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
В	Power Dissipation	250	mW
P _D	Derate Above 25°C	2.0	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	500	°C/W

Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu\text{A}, I_E = 0$	60			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{ mA}, I_B = 0$	50			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5			V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = 40 \text{ V}, I_{E} = 0$			0.1	μΑ
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 3 \text{ V}, I_{C} = 0$			0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = 6 \text{ V}, I_{C} = 1.0 \text{ mA}$	40		700	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$		0.15	0.30	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 6 \text{ V, } I_{C} = 10 \text{ mA}$		300		MHz
C _{ob}	Output Capacitance	$V_{CB} = 6 \text{ V}, I_{E} = 0,$ f = 1 MHz		2.5		pF
NF	Noise Figure	$\begin{split} &V_{\text{CE}} = 6 \text{ V, } I_{\text{C}} = 0.5 \text{ mA,} \\ &f = 1 \text{ kHz, } R_{\text{S}} = 500 \Omega \end{split}$		4.0		dB

h_{FE} Classification

ſ	Classification	R	0	Y	G	L
Г	h _{FF}	40 ~ 80	70 ~ 140	120 ~ 240	200 ~ 400	350 ~ 700

© 2002 Fairchild Semiconductor Corporation KSC945 Rev. 1.1.0

Typical Performance Characteristics

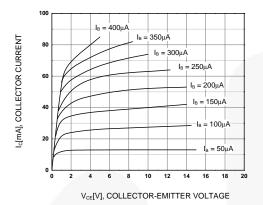


Figure 1. Static Characteristic

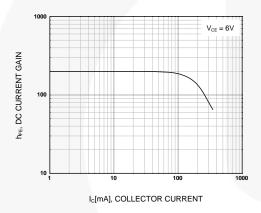


Figure 3. DC Current Gain

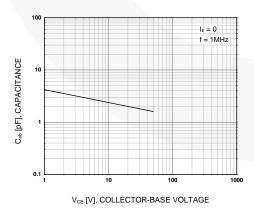


Figure 5. Output Capacitance

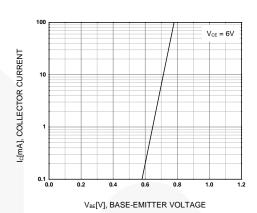


Figure 2. Transfer Characteristic

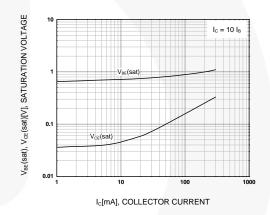


Figure 4. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

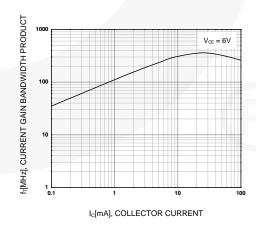
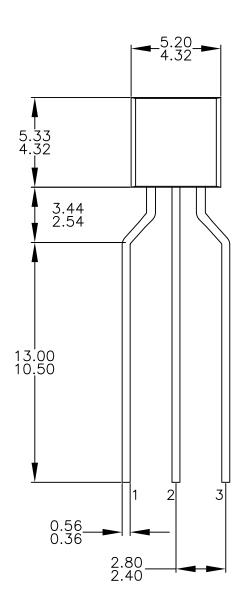
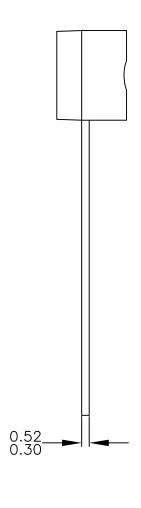
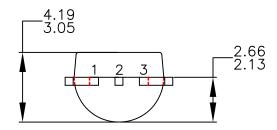


Figure 6. Current Gain Bandwidth Product

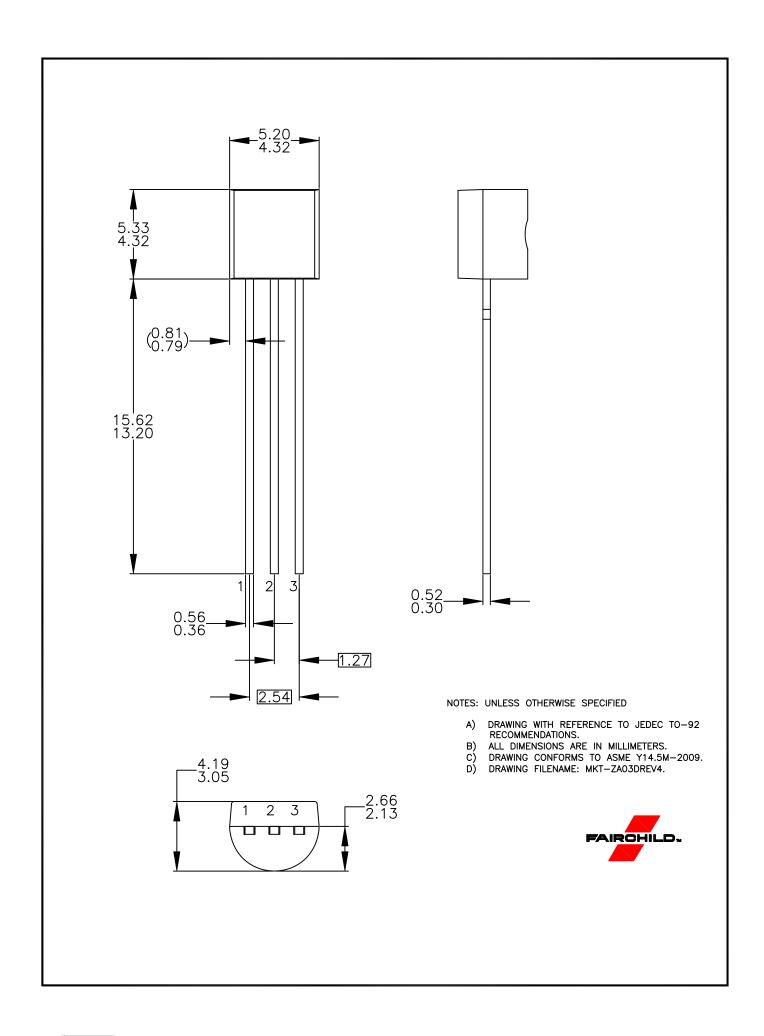






NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC.
 ALL DIMENSIONS ARE IN MILLIMETERS.
 DRAWING CONFORMS TO ASME Y14.5M-2009.
 DRAWING FILENAME: MKT-ZA03FREV3.
 FAIRCHILD SEMICONDUCTOR.



ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hol

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative